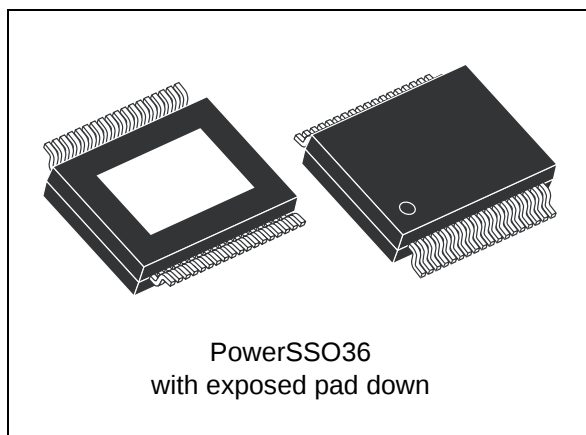


45 W + 45 W dual BTL class-D audio amplifier

Datasheet - production data



Features

- Wide-range single-supply operation (9 - 26 V)
- Possible output configurations:
 - 2 x PBTL
 - 1 x Parallel BTL
- BTL output capabilities ($V_{CC} = 22\text{ V}$):
 - 44 W + 44 W, 4 Ω , THD 1%
 - 57 W + 57 W, 4 Ω , THD 10%
 - 32 W + 32 W, 6 Ω , THD 1%
 - 41 W + 41 W, 6 Ω , THD 10%
 - 25 W + 25 W, 8 Ω , THD 1%
 - 32 W + 32 W, 8 Ω , THD 10%
- Parallel BTL output capabilities ($V_{CC} = 22\text{ V}$):
 - 70 W, 3 Ω , THD 1%
 - 90 W, 3 Ω , THD 10%
- High efficiency
- Four selectable, fixed gain settings of nominally 20.8 dB, 26.8 dB, 30 dB and 32.8 dB

- Differential inputs minimize common-mode noise
- Standby, mute and play operating mode
- Short-circuit protection
- Output power limited by PLIMIT function
- Output pins shorted detector during start-up
- Thermal overload protection
- ECOPACK[®], environmentally-friendly package

Description

The TDA7492PE is a dual BTL class-D audio amplifier with single power supply designed for Home Audio.

It comes in a 36 pin PowerSSO package with exposed pad down (EPD) to ease power dissipation through a properly designed PCB area underneath the TDA7492PE.

Table 1. Device summary

Order code	Operating temp. range	Package	Packaging
TDA7492PE	- 40 to 85 °C	PowerSSO36 (EPD)	Tube
TDA7492PETR	- 40 to 85 °C	PowerSSO36 (EPD)	Tape and reel

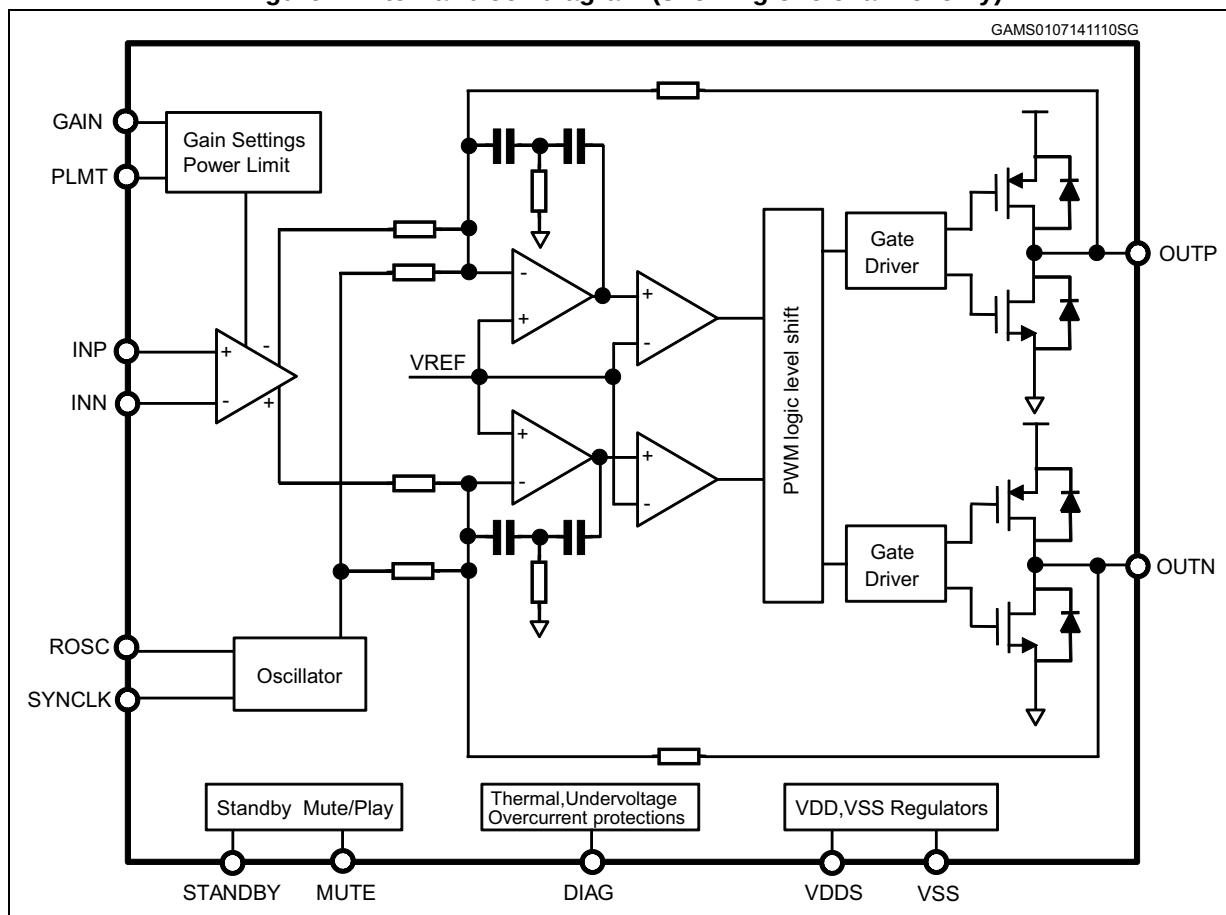
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1 Device block diagram

Figure 1 shows the block diagram of one of the two identical channels of the TDA7492PE.

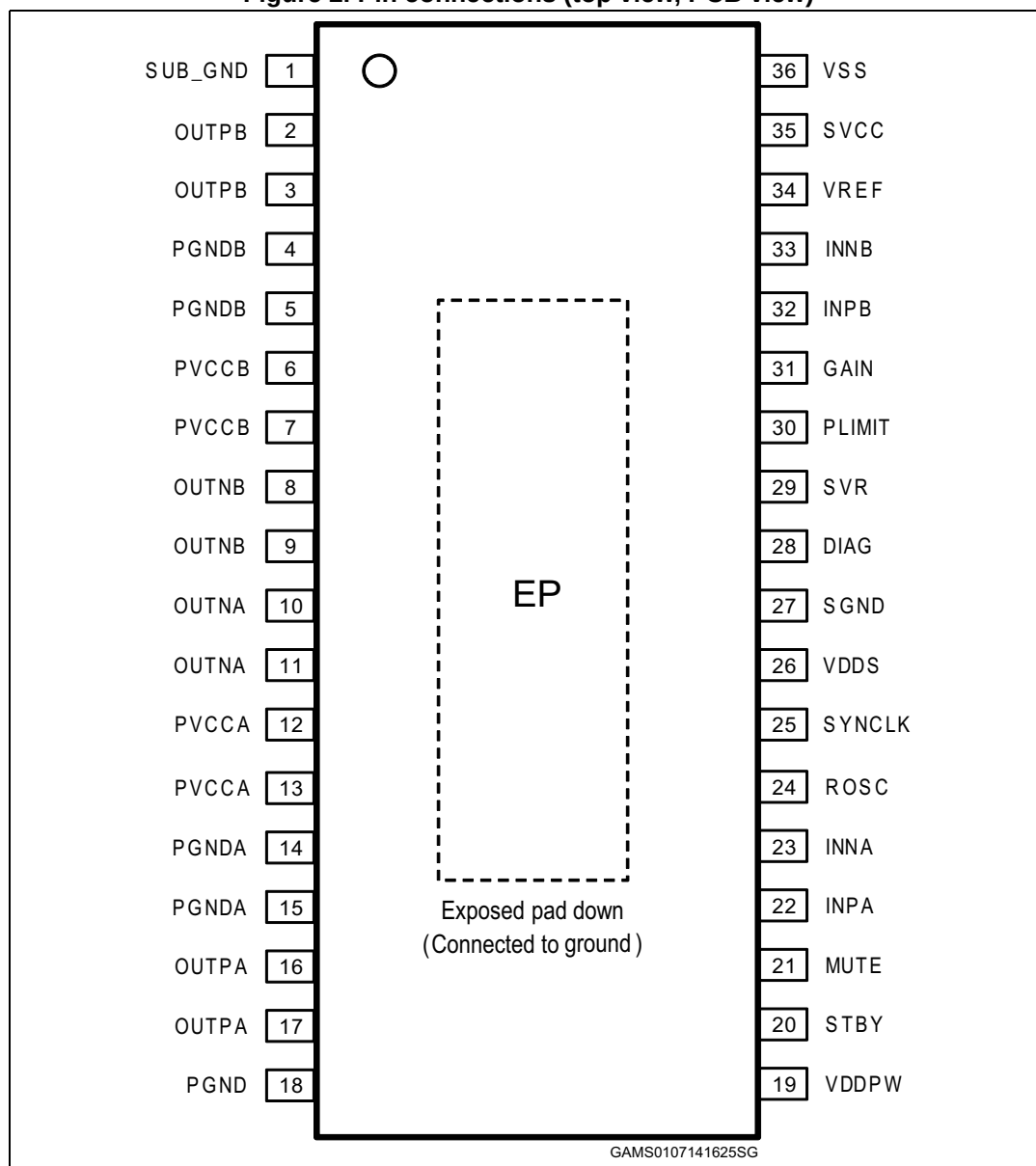
Figure 1. Internal block diagram (showing one channel only)



2 Pin description

2.1 Pin out

Figure 2. Pin connections (top view, PCB view)



2.2 Pin list

Table 2. Pin description list

Number	Name	Type	Description
1	SUB_GND	PWR	Connect to the frame
2,3	OUTPB	O	Positive PWM for right channel
4,5	PGNDB	PWR	Power stage ground for right channel
6,7	PVCCB	PWR	Power supply for right channel
8,9	OUTNB	O	Negative PWM output for right channel
10,11	OUTNA	O	Negative PWM output for left channel
12,13	PVCCA	PWR	Power supply for left channel
14,15	PGNDA	PWR	Power stage ground for left channel
16,17	OUTPA	O	Positive PWM output for left channel
18	PGND	PWR	Power stage ground
19	VDDPW	O	3.3 V (nominal) regulator output referred to ground for power stage
20	STBY	I	Standby mode control
21	MUTE	I	Mute mode control
22	INPA	I	Positive differential input of left channel
23	INNA	I	Negative differential input of left channel
24	ROSC	O	Master oscillator frequency-setting pin
25	SYNCLK	I/O	Clock in/out for external oscillator
26	VDDS	O	3.3 V (nominal) regulator output referred to ground for signal blocks
27	SGND	PWR	Signal ground
28	DIAG	O	Open-drain diagnostic output
29	SVR	O	Supply voltage rejection
30	PLIMIT	I	Output voltage level setting
31	GAIN	I	Gain setting input
32	INPB	I	Positive differential input of right channel
33	INNB	I	Negative differential input of right channel
34	VREF	O	Half VDDS (nominal) referred to ground
35	SVCC	PWR	Signal power supply
36	VSS	O	3.3 V (nominal) regulator output referred to power supply
-	EP	-	Exposed pad for heatsink, to be connected to ground

3 Electrical specifications

3.1 Absolute maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	DC supply voltage for pins PVCCA, PVCCB, SVCC	30	V
V_I	Voltage limits for input pins STBY, MUTE, INNA, INPA, INNB, INPB, GAIN, MODE	- 0.3 to 4.6	V
T_J	Operating junction temperature	- 40 to 150	°C
T_{op}	Operating ambient temperature	- 40 to 85	°C
T_{stg}	Storage temperature	- 40 to 150	°C

3.2 Thermal data

Table 4. Thermal data

Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{th\ j-case}$	Thermal resistance, junction to case	-	2.98		°C/W
$R_{th\ j-amb}$	Thermal resistance, junction to ambient ⁽¹⁾		24		°C/W

1. FR4 with vias to copper area of 9 cm²

3.3 Electrical specifications

Unless otherwise stated, the values in the table below are specified for the conditions:
 $V_{CC} = 22\text{ V}$, $R_L = 6\ \Omega$, $R_{OSC} = R_3 = 33\text{ k}\Omega$, $f = 1\text{ kHz}$, $G_V = 20.8\text{ dB}$ and $T_{amb} = 25\text{ }^\circ\text{C}$.

Table 5. Electrical specifications

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
V_{CC}	Supply voltage for pins PVCCA, PVCCB, SVCC		9		26	V
I_q	Total quiescent current	No LC filter, no load	-	40		mA
I_{qSTBY}	Quiescent current in standby	-	-	1		μA
V_{OS}	Output offset voltage	$V_i = 0$, no load	-20	-	20	mV
I_{OCP}	Overcurrent protection threshold to switch off the device		9	10	13	A
T_j	Junction temperature at thermal shutdown	-	140	150	160	$^\circ\text{C}$
R_i	Input resistance	Differential input		60	-	k Ω
R_{dsON}	Power transistor on resistance	High side	-	0.2	-	Ω
		Low side	-	0.2	-	
G_V	Closed-loop gain	$GAIN < 0.25 \cdot V_{DD}$		20.8		dB
		$0.25 \cdot V_{DD} < GAIN < 0.5 \cdot V_{DD}$		26.8		
		$0.5 \cdot V_{DD} < GAIN < 0.75 \cdot V_{DD}$		30		
		$GAIN > 0.75 \cdot V_{DD}$		32.8		
ΔG_V	Gain matching	-		-	± 1	dB
C_T	Crosstalk	$f = 1\text{ kHz}$, $P_o = 1\text{ W}$		70	-	dB
SVRR	Supply voltage rejection ratio	$f_r = 100\text{ Hz}$, $V_r = 0.5\text{ V}_{pp}$, $C_{SVR} = 10\ \mu\text{F}$	-	60	-	dB
T_r , T_f	Rise and fall times	-	-	40	-	ns
f_{SW}	Switching frequency	Internal oscillator		500		kHz
f_{SWR}	Output switching frequency range	With internal oscillator by changing $R_{osc}^{(1)}$	450	-	550	kHz
V_{inH}	Digital input high (H)	-	2.0	-	-	V
V_{inL}	Digital input low (L)		-	-	0.8	
Function mode	Standby & mute & play	STBY < 0.5 V, MUTE = X	Standby			
		STBY > 2.5 V; MUTE < 0.8 V	Mute			
		STBY > 2.5 V, MUTE > 2.5 V	Play			
A_{MUTE}	Mute attenuation	$V_{MUTE} = 1\text{ V}$	60	80	-	dB

1. $f_{SW} = 10^6 / ((R_{OSC} \cdot 12 + 110) \cdot 4)\text{ kHz}$, $f_{SYNCLK} = 2 \cdot f_{SW}$ (where R_{OSC} is in k Ω and f_{SW} in kHz) with $R_{OSC} = 33\text{ k}\Omega$.

3.4 Stereo BTL application

All specifications are for $V_{CC} = 22\text{ V}$, $R_{OSC} = 33\text{ k}\Omega$, $f = 1\text{ kHz}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified.

Table 6. Stereo BTL application

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
P_o	Output power	$R_L = 6\text{ }\Omega$, THD = 10%	-	41	-	W
		$R_L = 6\text{ }\Omega$, THD = 1%	-	32	-	
	Output power	$R_L = 6\text{ }\Omega$, THD = 10%, $V_{CC} = 18\text{ V}$	-	27	-	
		$R_L = 6\text{ }\Omega$, THD = 1%, $V_{CC} = 18\text{ V}$	-	21	-	
THD	Total harmonic distortion	$P_o = 1\text{ W}$, $f_{in} = 1\text{ kHz}$	-	0.04	-	%
VN	Total output noise	Inputs shorted and connected to GND, A Curve, $G_V = 20.8\text{ dB}$	-	150	-	μV

3.5 Parallel BTL (mono) application

All specifications are for $V_{CC} = 22\text{ V}$, $R_{OSC} = 33\text{ k}\Omega$, $f = 1\text{ kHz}$, $T_{amb} = 25\text{ }^{\circ}\text{C}$, INPB, INNB connected to VDDS, unless otherwise specified

Table 7. Mono BTL application

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
P_o	Output power	$R_L = 3\text{ }\Omega$, THD = 10%,	-	90	-	W
		$R_L = 3\text{ }\Omega$, THD = 1%	-	70	-	
	Output power	$R_L = 3\text{ }\Omega$, THD = 10%, $V_{CC} = 18\text{ V}$	-	53	-	
		$R_L = 3\text{ }\Omega$, THD = 1%, $V_{CC} = 18\text{ V}$	-	41	-	
THD	Total harmonic distortion	$P_o = 1\text{ W}$, $f_{in} = 1\text{ kHz}$	-	0.04	-	%
VN	Total output noise	Inputs shorted and connected to GND, A Curve, $G_V = 20.8\text{ dB}$	-	150	-	μV

4 Application information

4.1 Gain setting

The four gain setting of the TDA7492PE is set by the GAIN (pin 31). Internally, the gain is set by changing the feedback resistors of the amplifier. The gain setting pins can be controlled by standard logic drives.

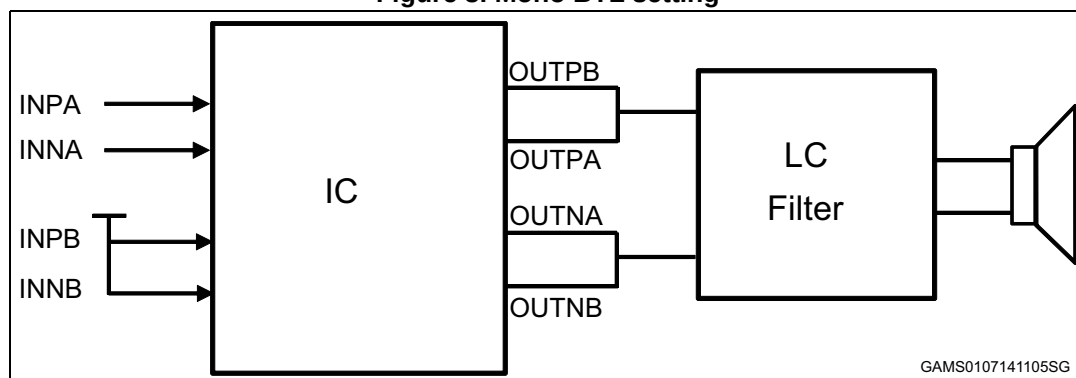
Table 8. Gain settings

Voltage on GAIN pin	Total GAIN	Application Suggestions
$V_{\text{GAIN}} < 0.25 \cdot V_{\text{DDDS}}$	20.8 dB	Pin "GAIN" connected to SGND
$0.25 \cdot V_{\text{DDDS}} < V_{\text{GAIN}} < 0.5 \cdot V_{\text{DDDS}}$	26.8 dB	External resistor divider <100 k
$0.5 \cdot V_{\text{DDDS}} < V_{\text{GAIN}} < 0.75 \cdot V_{\text{DDDS}}$	30 dB	External resistor divider <100 k
$V_{\text{GAIN}} > 0.75 \cdot V_{\text{DDDS}}$	32.8 dB	Pin "GAIN" connected to VDDDS

4.2 Stereo and Mono application

The TDA7492PE can be used in Stereo BTL or in MONO BTL configuration. When the input pins, INPB and INNB of the right Channel are directly shorted to VDDDS (without input capacitors) the device is in MONO configuration as shown in [Figure 3](#).

Figure 3. Mono BTL setting



4.3 Smart protections

4.3.1 Over-current protection (OCP)

In case the over-current protection threshold is reached, the power stage will be shutdown immediately. The device will recover automatically when the fault is removed.

Table 9. Overcurrent protection

	I (Shutdown)
High side (A)	11.2
Low side (A)	10.0

The thresholds in MUTE Mode are reduced to about 1/2 and two typical thresholds are as follows.

Table 10. Overcurrent protection (mute mode)

	I (Shutdown)
High side (A)	6.2
Low side (A)	5.9

4.3.2 Thermal protection

When internal die temperature exceeds 140°C, the device enters into Mute by pulling MUTE pin low firstly.

When internal die temperature exceeds 150°C, the device directly shuts down the power stage. The TDA7492PE automatically recovers when the temperature become lower than the threshold.

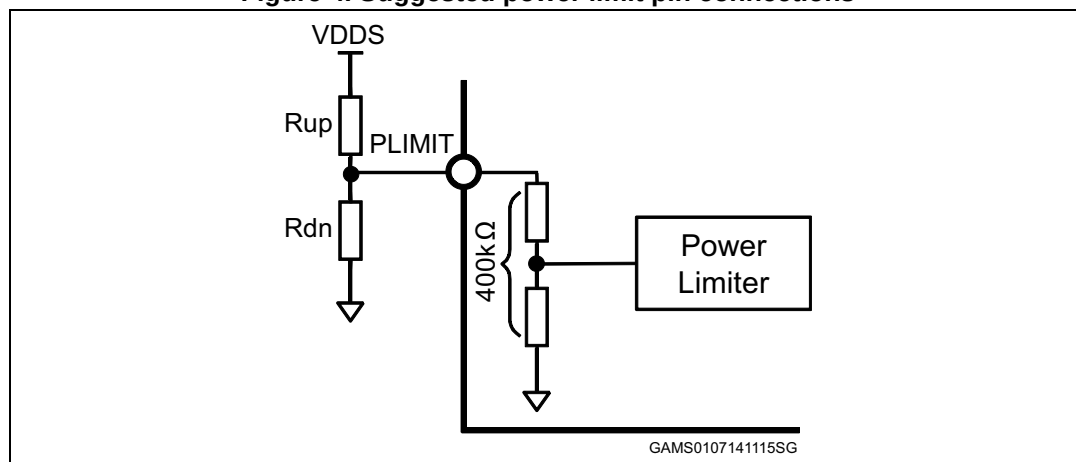
4.3.3 Power limit

A built-in power limit is used to limit the output voltage level below the supply rail by limiting the duty cycle. The limit level is set through the voltage at the PLIMIT (pin.30). The pin voltage is set by the following equation:

Equation 1

$$VPILIMIT = VDDS = [(Rdn//400k) / (Rdn//400k + Rup)]$$

Figure 4. Suggested power limit pin connections



It is recommended that external resistors are less than 40 kΩ if voltage divider is used as shown in [Figure 4](#). The relationship of the maximum duty cycle (Dmax) and the voltage at PLIMIT is:

Equation 2

$$D_{\max} = \left(8.8 \times \frac{V_{\text{PLIMIT}}}{V_{\text{CC}} - \frac{2 \times V_{\text{CC}} \times R_{\text{s}}}{R_{\text{load}} \times 2 \times R_{\text{s}}}} + 1 \right) / 2$$

Where V_{CC} is the power supply voltage, V_{PLIMIT} is the voltage applied at PLIMIT pin, R_{s} is the series resistance including R_{dson} of power transistor. R_{load} is the load resistance.

An example of maximum effective control voltage at PLIMIT vs. power supply and load resistance is shown in [Table 11](#).

Table 11. Max effective voltage of P_{LIMIT} pin vs. power supply and load

Rload	Power supply		
	7 V	13 V	24 V
4 Ω	0.71 V	1.32 V	2.44 V
6 Ω	0.74 V	1.37 V	2.53 V
8 Ω	0.75 V	1.39 V	2.57 V

4.4 Mode selection

The three operating modes of the TDA7492PE are set by the two inputs STBY (pin 20) and MUTE (pin 21).

- Standby mode: all circuits are turned off very low current consumption.
- Mute mode: inputs are connected to ground and the positive and negative PWM outputs are at 50% duty cycle
- Play mode: the amplifiers are active.

The protection functions of the TDA7492PE are realized by pulling down the voltages of the STBY and MUTE inputs shown in figure. The input current of the corresponding pins must be limited to 200 μA.

Table 12. Mode settings

Mode	STBY	MUTE
Standby	L ⁽¹⁾	X (don't care)
Mute	H	L
Play	H	H

1. Drive levels defined in Table.5: Electrical specifications on page 7.

Figure 5. Standby and mute circuits

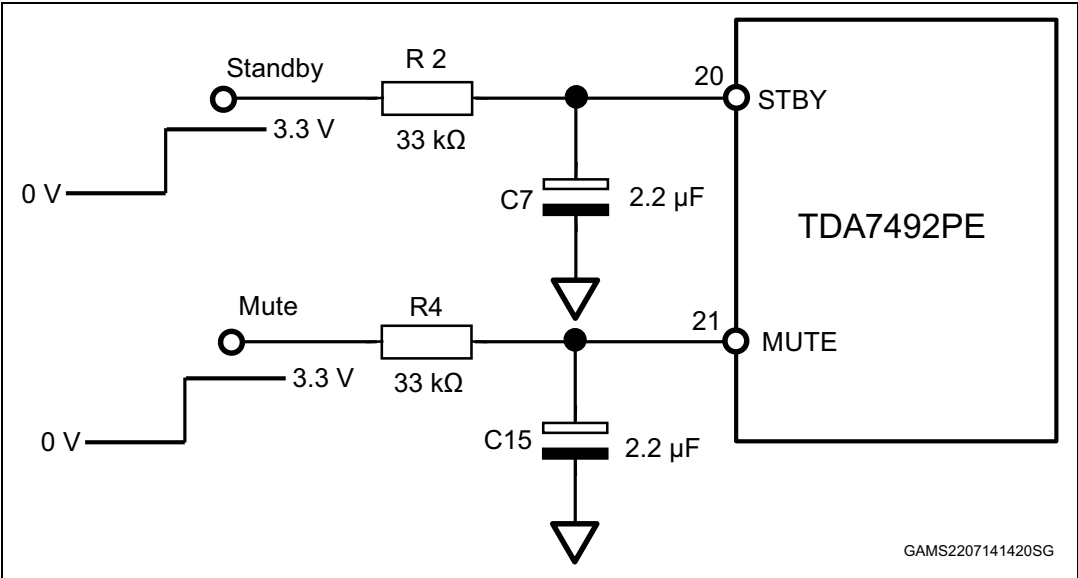


Figure 6. Turn-on/off sequence for minimizing speaker “pop”

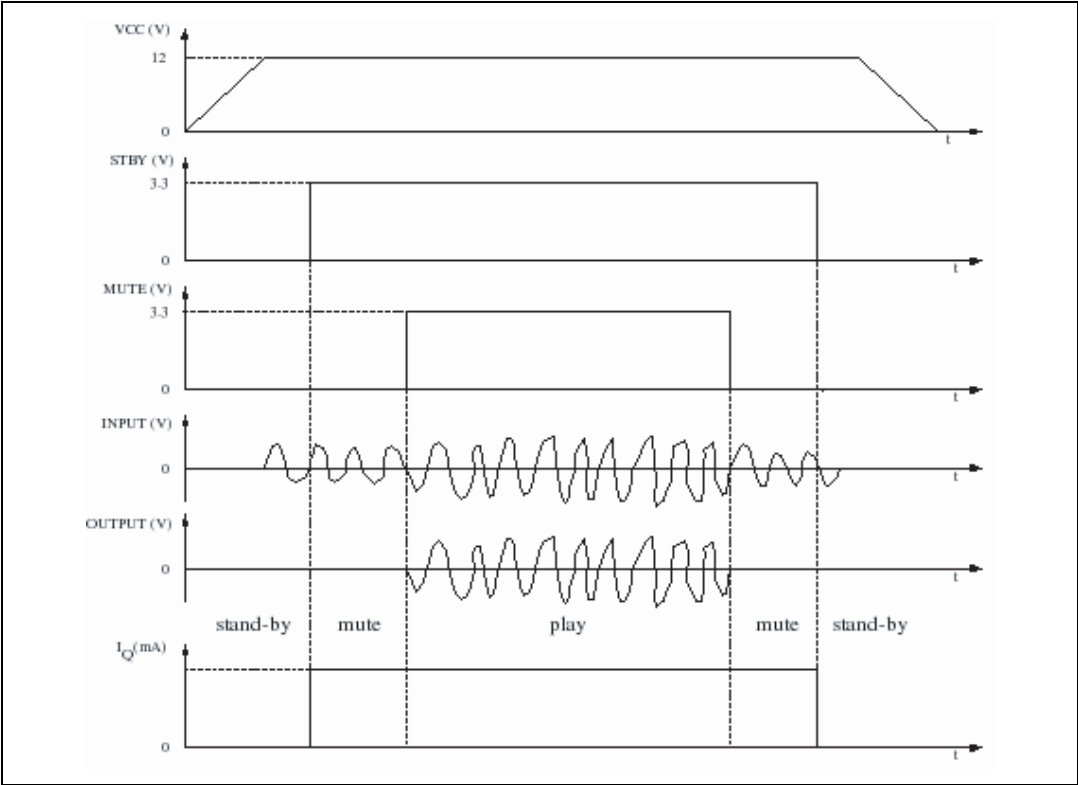


Figure 7. Application circuit

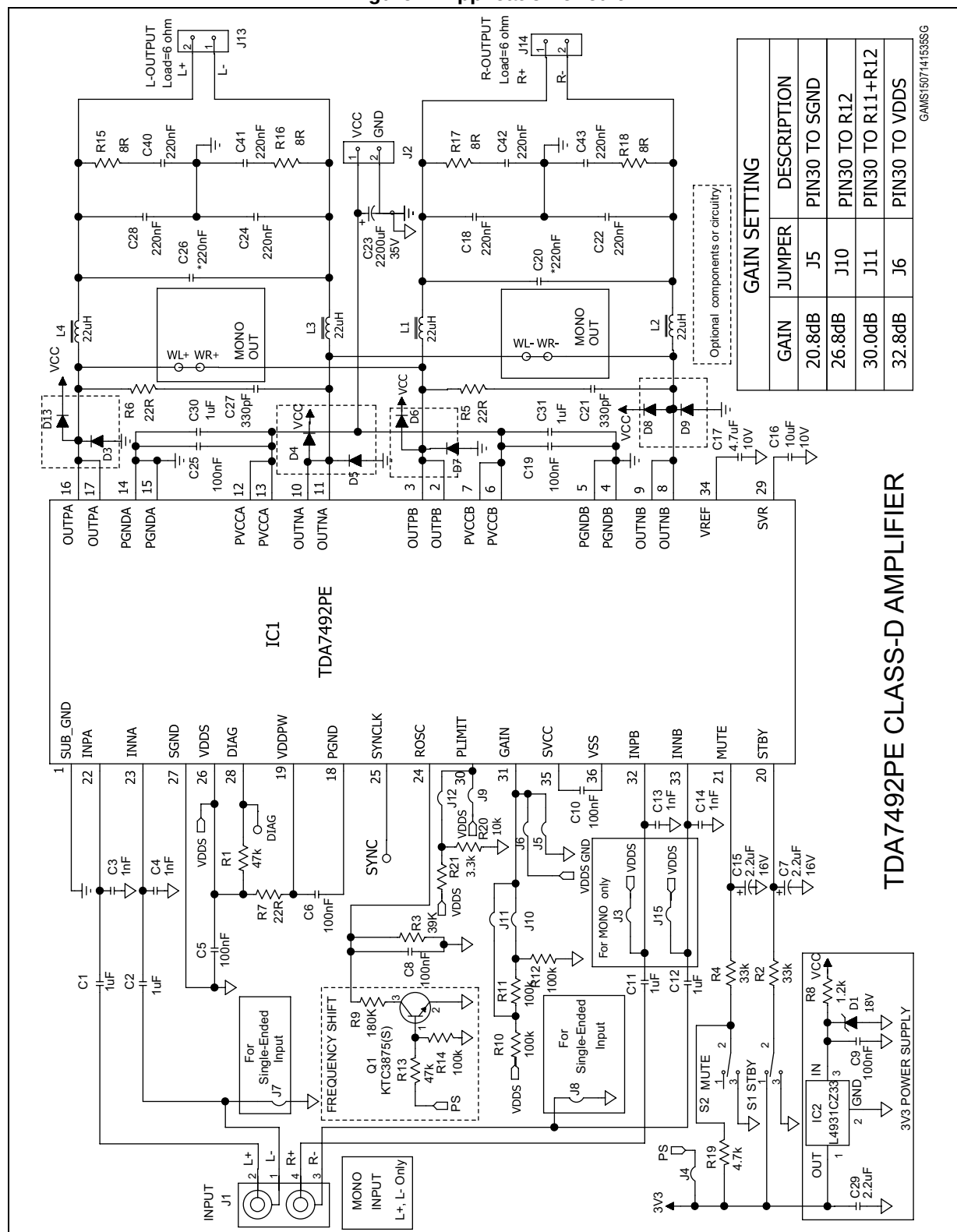


Figure 7. Application circuit

Table 13. BTL configuration

Load impedance	L4, L3, L2, L1	C26, C20	C28, C24, C22, C18	R15, R16, R17, R18	C40, C41, C42, C43
4 Ω	15 μ h	1 μ F	220 nF	8 Ω	220 nF
6 Ω	22 μ h	680 nF	220 nF	8 Ω	220 nF
8 Ω	22 μ h	470 nF	220 nF	8 Ω	220 nF

6 Characterization curves

Unless otherwise stated, measurements were made under the following conditions:
 $V_{CC} = 22\text{ V}$, $R_I = 6\ \Omega$, $f = 1\text{ kHz}$, $G_v = 20.8\text{ dB}$, $R_{OSC} = 33\text{ k}\Omega$, $T_{amb} = 25\text{ }^\circ\text{C}$.

Note: Maximum output power must be derated according to case temperature.

Figure 8. Supply voltage vs. output power

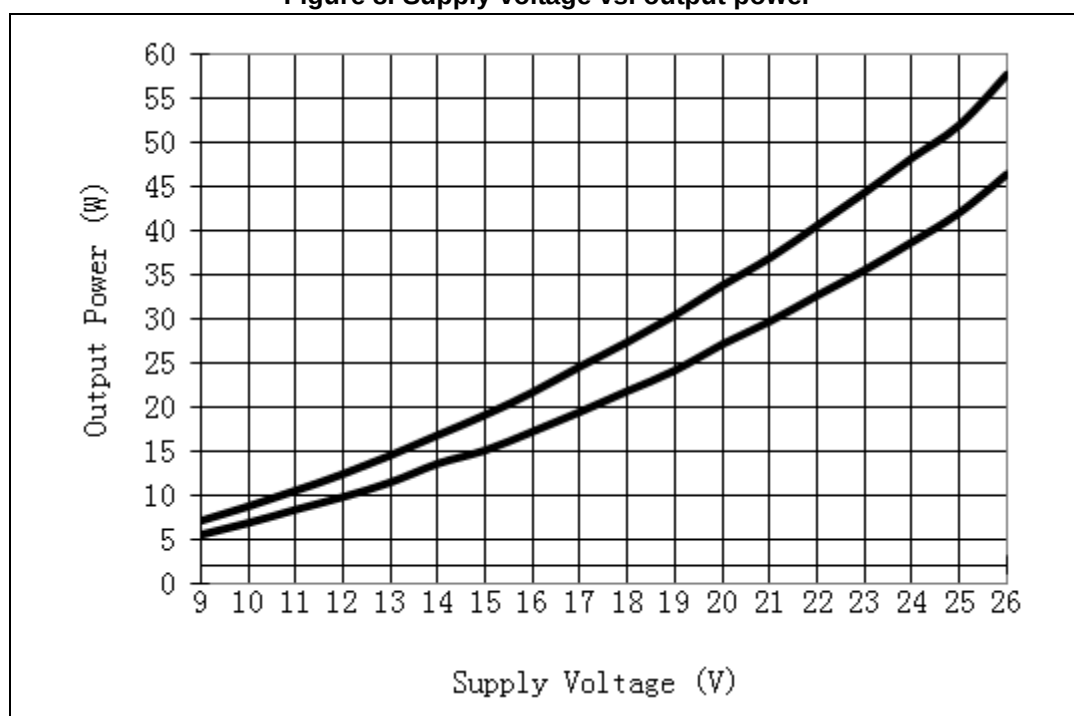


Figure 9. Efficiency vs. output power

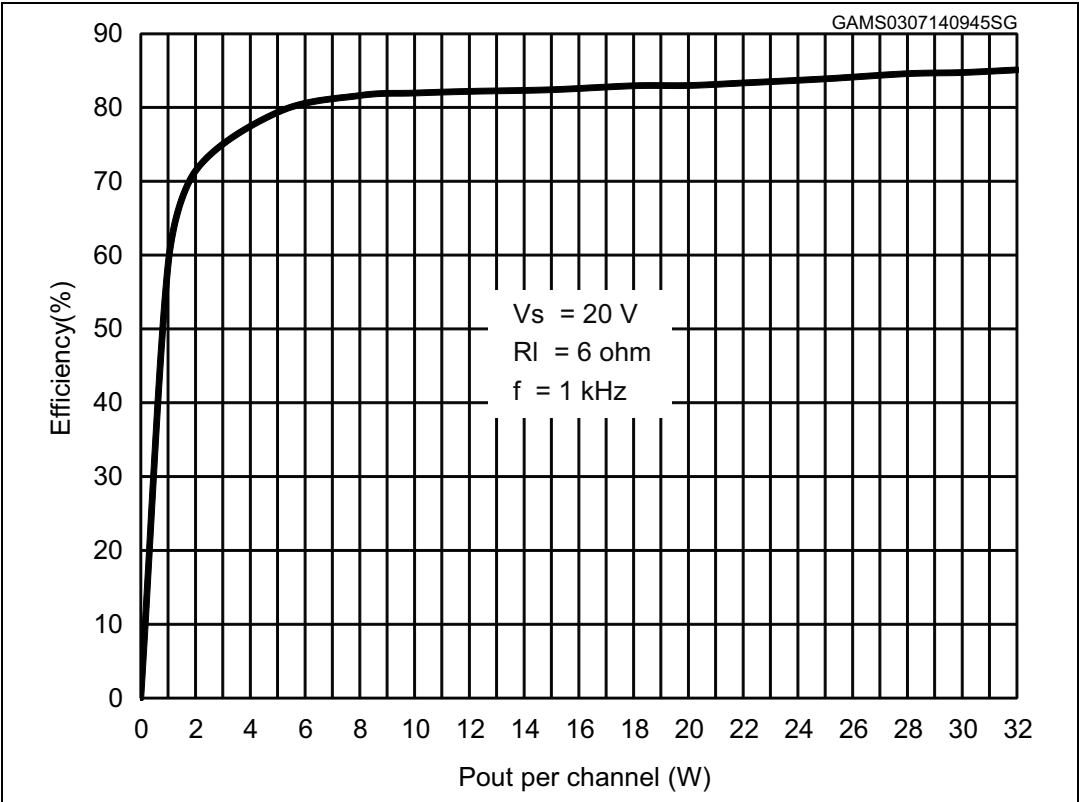


Figure 10. THD vs. output power (f = 1 kHz)

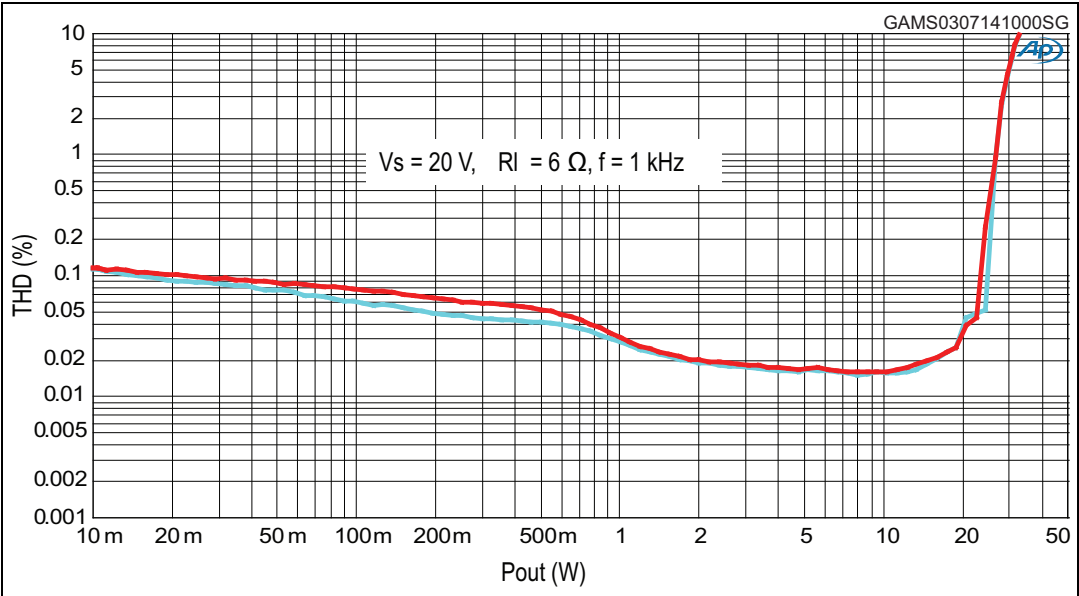


Figure 11. THD vs. output power (100 Hz)

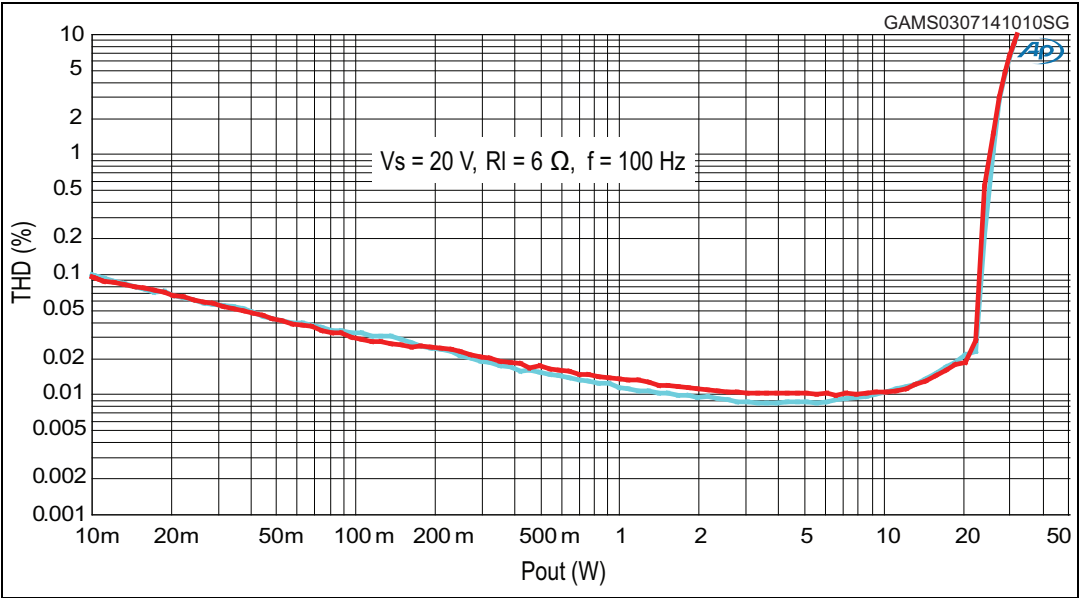


Figure 12. THD vs. frequency

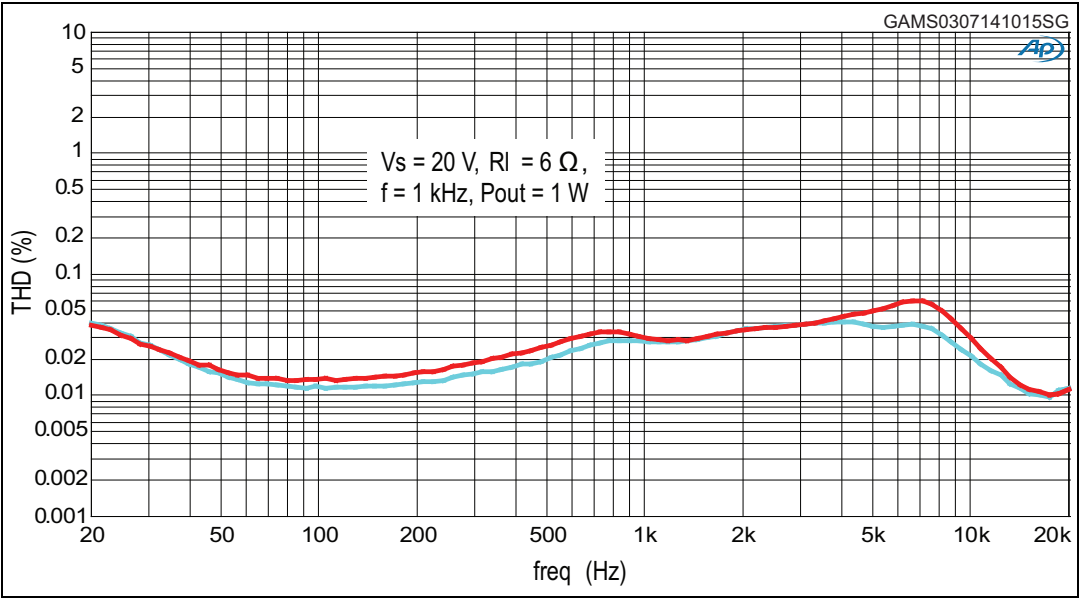


Figure 13. Frequency response

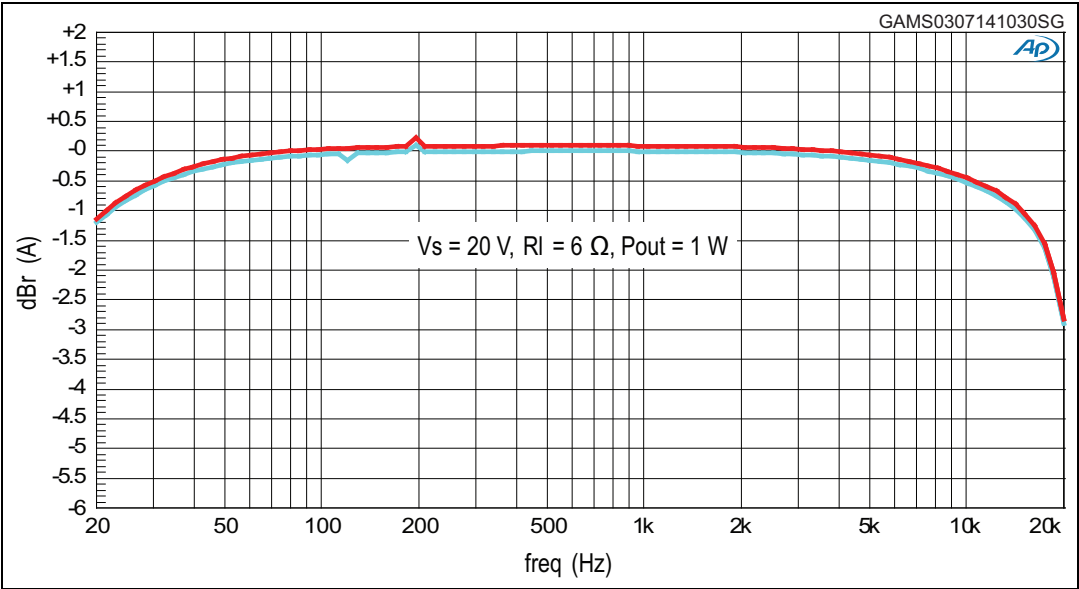


Figure 14. FFT (0 dB)

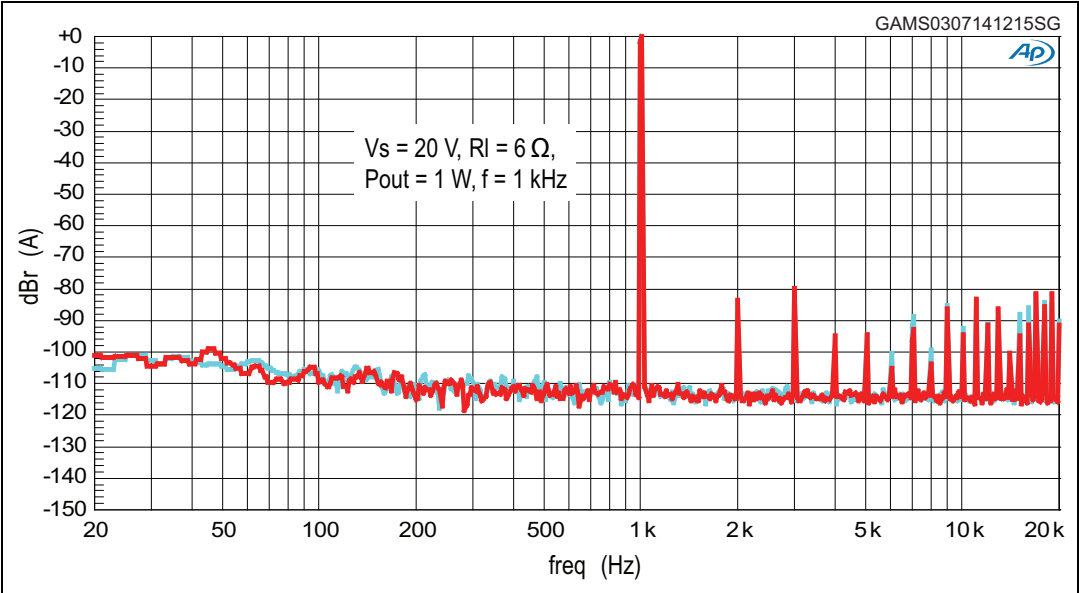


Figure 15. FFT (- 60 dB)

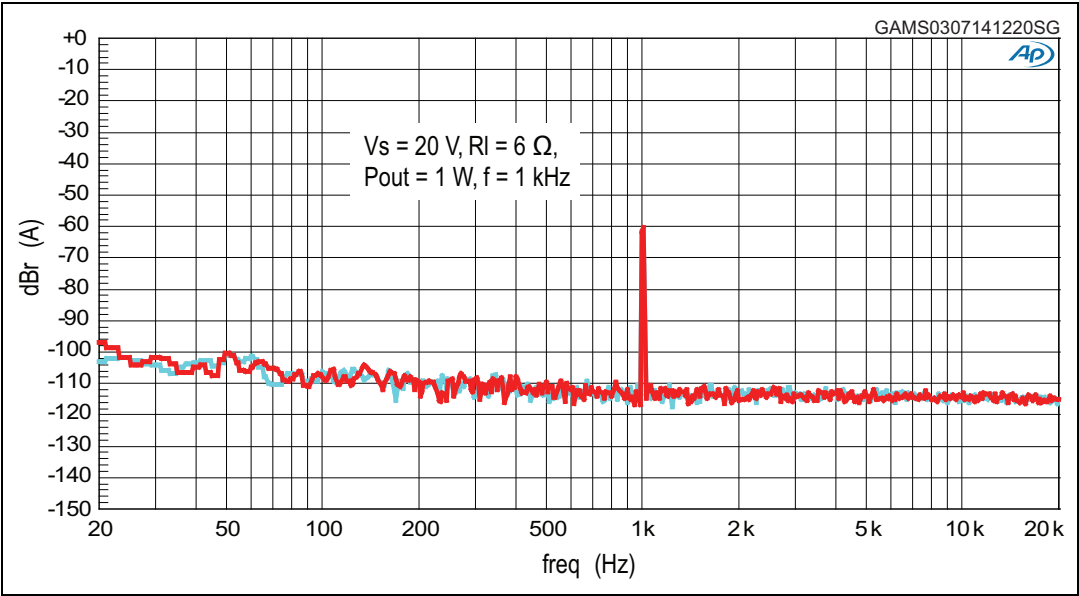
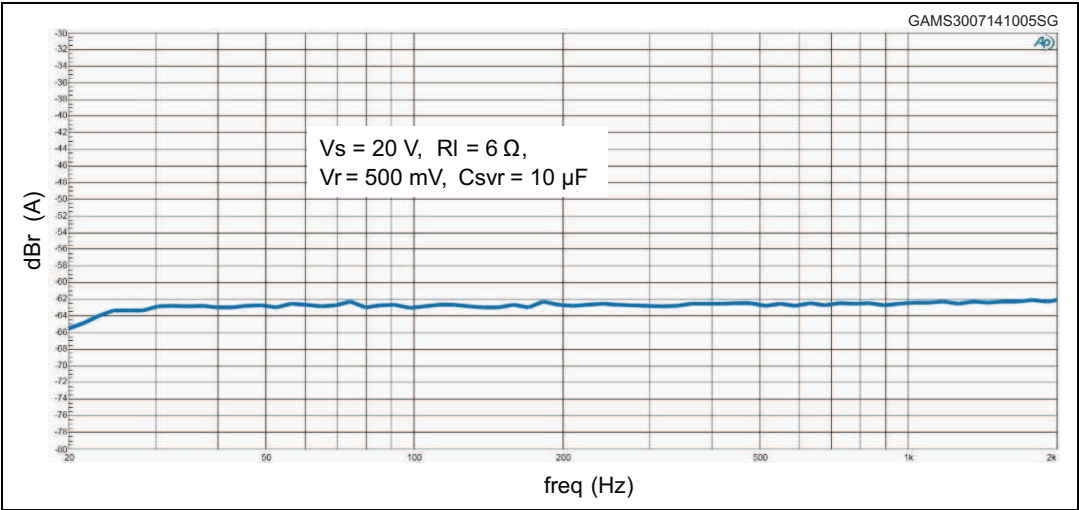


Figure 16. PSRR parameter



7 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

The TDA7492PE comes in a 36-pin PowerSSO package with exposed pad down.

[Figure 17](#) shows the package outline and [Table 14](#) gives the dimensions.

Figure 17. PowerSSO36 EPU outline drawing

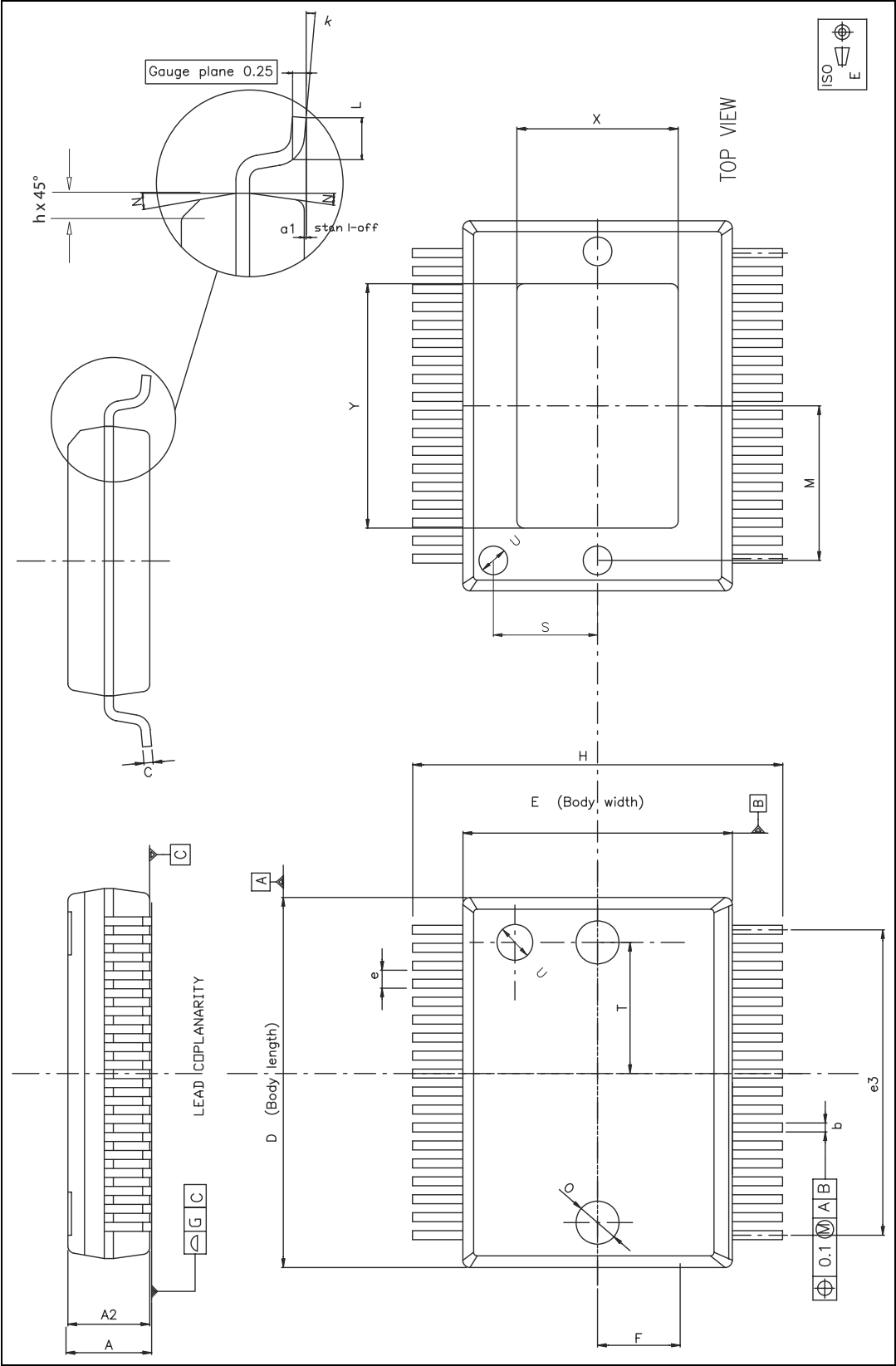


Table 14. Power SSO36EPD dimensions

Symbol	Dimensions in mm			Dimensions in inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.15	-	2.45	0.085	-	0.096
A2	2.15	-	2.35	0.085	-	0.093
a1	0	-	0.10	0	-	0.004
b	0.18	-	0.36	0.007	-	0.014
c	0.23	-	0.32	0.009	-	0.013
D	10.10	-	10.50	0.398	-	0.413
E	7.40	-	7.60	0.291	-	0.299
e	-	0.5	-	-	0.020	-
e3	-	8.5	-	-	0.335	-
F	-	2.3	-	-	0.091	-
G	-	-	0.10	-	-	0.004
H	10.10	-	10.50	0.398	-	0.413
h	-	-	0.40	-	-	0.016
k	0	-	8 degrees	0	-	8 degrees
L	0.60	-	1.00	0.024	-	0.039
M	-	4.30	-	-	0.169	-
N	-	-	10 degrees	-	-	10 degrees
O	-	1.20	-	-	0.047	-
Q	-	0.80	-	-	0.031	-
S	-	2.90	-	-	0.114	-
T	-	3.65	-	-	0.144	-
U	-	1.00	-	-	0.039	-
X	4.10	-	4.70	0.161	-	0.185
Y	4.90	-	7.10	0.193	-	0.280

8 Revision history

Table 15. Document revision history

Date	Revision	Changes
17-Nov-2014	1	Initial release.

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